

**UNIVERSITY COLLEGE TATI (UC TATI)****FINAL EXAMINATION QUESTION BOOKLET**

COURSE CODE	: BMT 1043
COURSE	: ELECTRONICS
SEMESTER/SESSION	: 2-2023/2024
DURATION	: 3 HOURS

**Instructions:**

1. This booklet contains 4 questions. Answer **ALL** the questions.
2. All answers should be written in answer booklet.
3. Write legibly and draw sketches wherever required.
4. If in doubt, raise your hands and ask the invigilator.

**DO NOT OPEN THIS BOOKLET UNTIL YOU ARE TOLD TO DO SO**

**THIS BOOKLET CONTAINS 8 PRINTED PAGES INCLUDING COVER PAGE**

**QUESTION 1**

- a) Answer the following questions:
- List **three (3)** types of material classification. (3 marks)
  - Give an example for every material classification. (3 marks)
- b) Draw the reversed bias diode circuit. (3 marks)
- c) A silicon diode is connected in DC series configuration as shown in Figure 1. Determine:
- The current  $I$  (4 marks)
  - The voltage at  $V_1$  (2 marks)
  - The voltage at  $V_2$  (2 marks)
  - The voltage at  $V_o$  (2 marks)

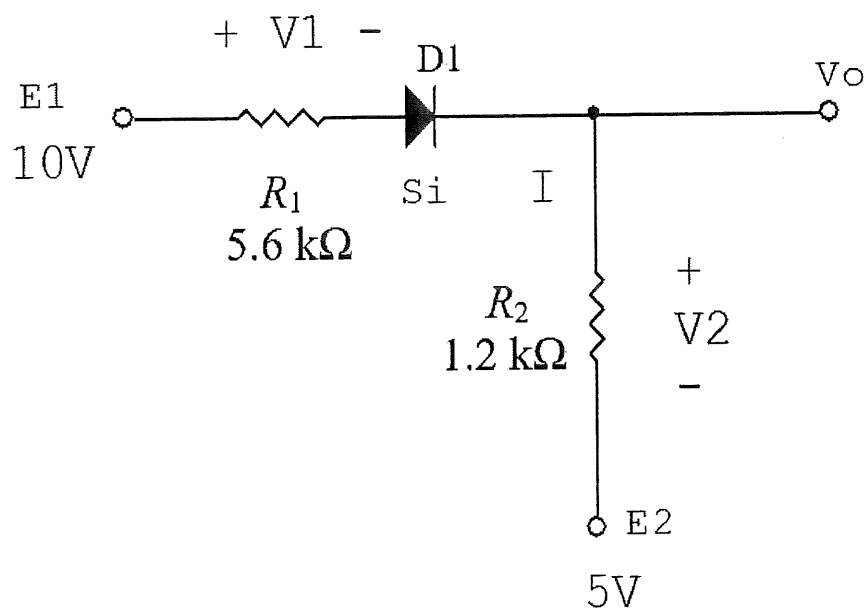
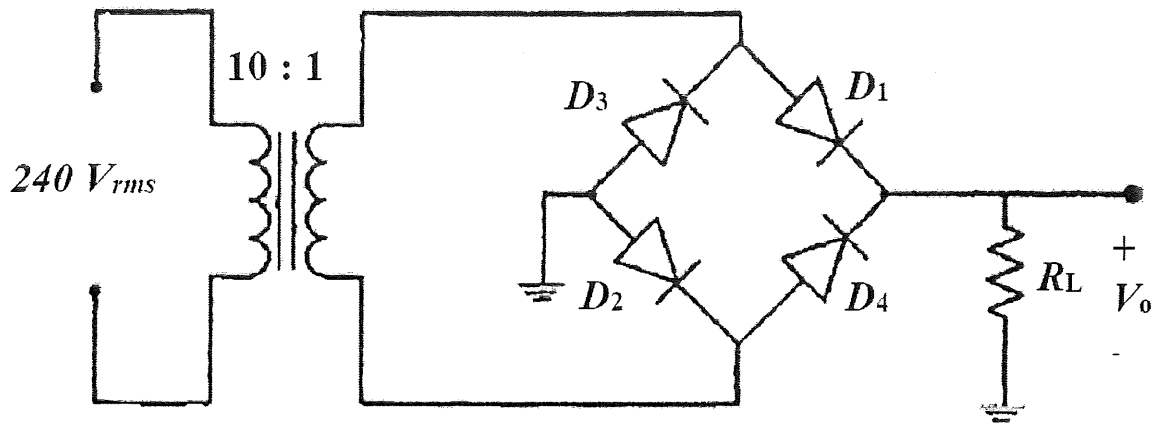


Figure 1

**QUESTION 2**

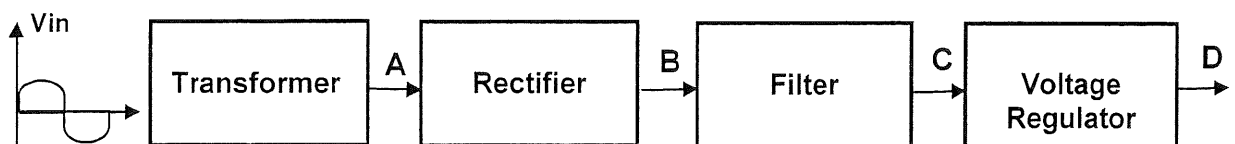
a) Figure 2 shows some parts of a power supply circuit. Assume that the diodes  $D_1 - D_4$  are silicon:



**Figure 2**

- i. State the function of the bridge network  $D_1 - D_4$  (2 marks)
- ii. Explain briefly the operation of the bridge network (6 marks)
- iii. Sketch the waveform at the output,  $V_o$  (4 marks)

b) Figure 3 shows the major parts of a power supply unit. Draw the output waveform at point A, B, C, and D. (5 marks)



**Figure 3**

- c) A bipolar junction transistor is a combination of two junction diode from a P-type material and N-type of material. Answer the following questions:
- i. Draw a PNP and NPN transistor that connected to the battery and show the current flow of each of the transistor accordingly (4 marks)
  - ii. Figure 4 show a bipolar junction transistor circuit. Given that  $V_O = 4V$ ,  $\beta = 150$  and  $V_{BE} = 0.7V$ . Determine the voltage at  $V_s$  (7 marks)

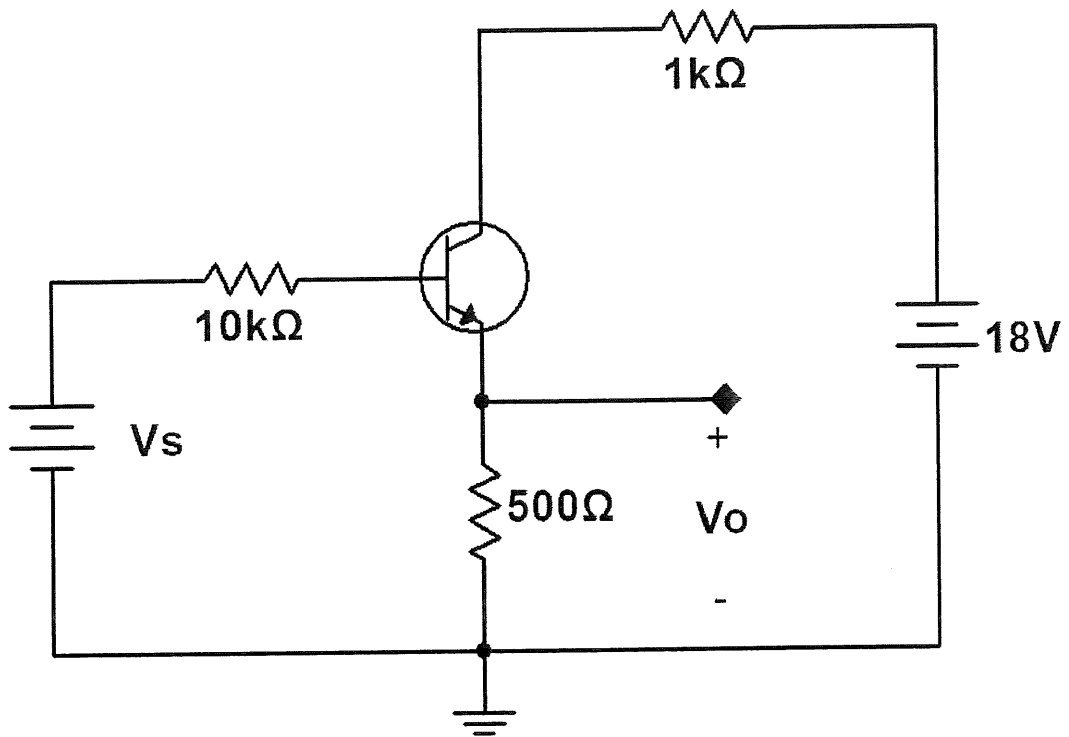


Figure 4

- d) For the circuit shown in Figure 5, given,  $\beta_{ac} = 120$ . Answer all the followings:
- Solve the Q-point ( $I_{CQ}$  and  $V_{CEQ}$ ). (5 marks)
  - Compute the emitter voltage,  $V_E$ . (2 marks)

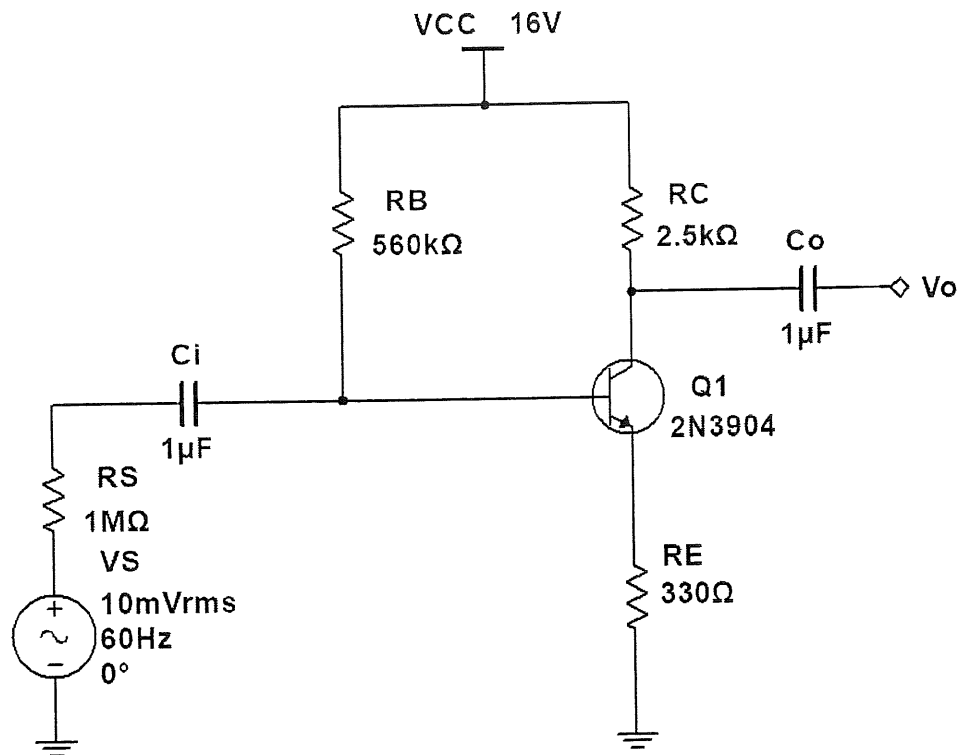


Figure 5

## QUESTION 3

- a) Express **three (3)** operation modes available for bipolar junction transistor (**BJT**).  
(3 marks)
- b) Figure 6 shows a collector characteristic curve for the Q-point operation for the **fixed-bias network**.  
(2 marks)
- Find the Q-point ( $I_{CQ}$  and  $V_{CEQ}$ ).  
(3 marks)
  - Determine the value of  $V_{CC}$ .  
(6 marks)
  - Determine the value of  $R_B$  and  $R_C$ .  
(6 marks)

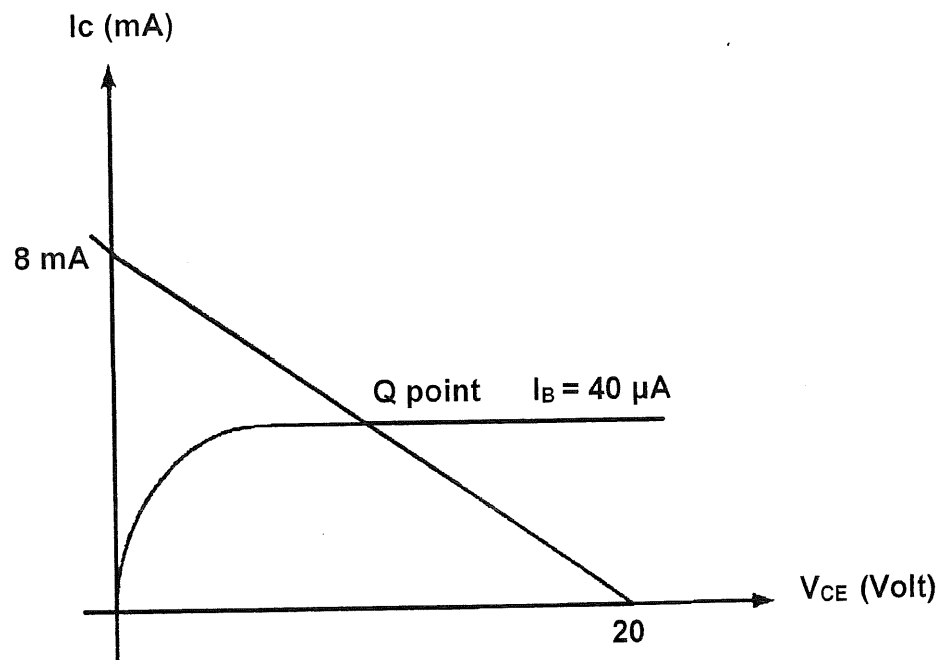


Figure 6

## QUESTION 4

- a) The input impedance,  $Z_i$  to a common-emitter transistor amplifier as shown in Figure 7 is  $1.2 \text{ k}\Omega$  with  $\beta = 120$
- Draw an AC equivalent circuit. (2 marks)
  - Calculate the impedance,  $r_e$  (2 marks)
  - Calculate the base current,  $I_b$  if  $V_i = 30 \text{ mV}$  (4 marks)

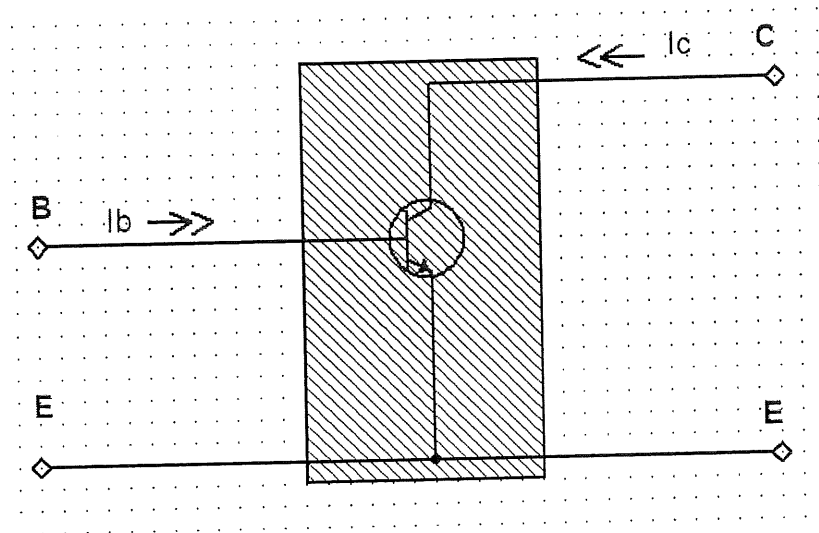


Figure 7

- b) Answer the following questions:
- Describe the term dc beta ( $\beta$ ) and dc alpha ( $\alpha$ ). (3 marks)
  - Describe the relationship between  $\alpha$  and  $\beta$ . (2 marks)
- c) Refer to the voltage divider system of Figure 8. Given  $\beta = 150$ .
- Compute the Q-point ( $I_{CQ}$  and  $V_{CEQ}$ ) (8 marks)
  - Compute base voltage,  $V_B$  and emitter voltage,  $V_E$ . (3 marks)
  - Find the value of  $r_e$ . (2 marks)
  - Draw the ac equivalent circuit for the network of Figure 7. (2 marks)
  - Analyze the voltage gain,  $A_v = V_{out}/V_{in}$ . (4 marks)

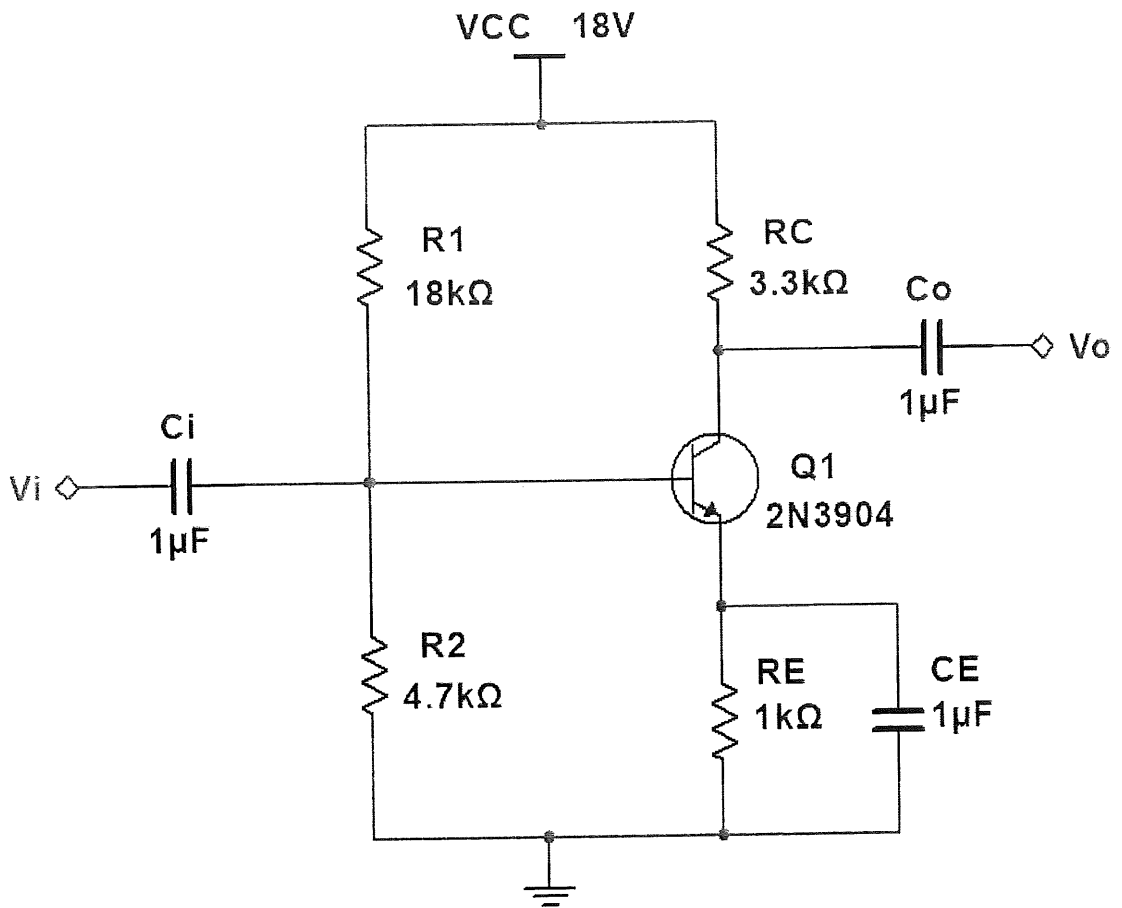


Figure 8

-----End of question-----